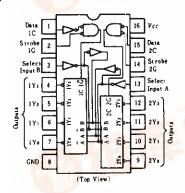
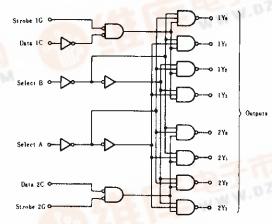
# ### 接多邦,专业PCB打样工厂,24小时加急 Decoders/Demultiplexers (with open collector outputs)

This circuit features dual 1-line-to-4-line demultiplexer with individual strobes and common binary-address inputs. When both sections are enabled by the strobes, the common binaryaddress inputs sequentially select and route associated input data to the appropriate output of each section. The individual strobes permit activating or inhibiting each of the 4-bit sections as desired. Data applied to input 1C is inverted through its outputs. The inverter following the 1C data input permits use as a 3-to-8-line decoder or 1-to-8-line demultiplexer without external gating.

### **PIN ARRANGEMENT**



#### **■BLOCK DIAGRAM**



#### RECOMMENDED OPERATING CONDITIONS

Item	Symbol	min	typ	max	Unit
High level output voltage	<b>V</b> oн	_	-	5.5	v
Low level output current	lou			8	mA

#### **EFUNCTION TABLE**

#### ●2-to-4-line Decoder/1-to-4-line Demultiplexer

		Inputs		Outputs			Inputs				Outputs				
SEL	ECT	STROBE	DAΤA		1			SEL	ECT	STROBE	DATA				
В	Α	1G	1C	1Y0	1Y1	1Y2	1Y3	В	Α	2G	2C	2Y0	2Y1	2Y2	2Y3
×	×	Н	×	Н	Н	Н	H	×	×	н	×	H	Н	Н	Н
L	L	L	H	I.	Н	Н	Н	L	L	L	L	L	Н	Н	Н
L	Н	L	Н	Н	l,	Н	Н	L	Н	L.	L	н	L	Н	Н
Н	L	L	Н	Н	Н	L	Н	Н	L	L	L	·H	Н	L	Н
Н	Н	L	H	Н	Н	Н	Ĺ.	Н	Н	L	L	Н	н	н	L
×	×	×	I.	Н	Н	Н	Н	×	×	×	Н	Н	Н	Н	Н

#### ●3-to-8-line Decoder/1-to-8-line Demultiplexer

	Inputs			Outputs									
	SELECT		STROBE OR DATA	(0)	(1)	(2)	(3)	(4)	(5)	(6)	(7)		
C1)	В	Α	G <sub>2</sub> )	2Y0	2Y1	2Y2	2Y3	1Y0	171	1Y2	1Y3		
×	×	×	Н	H	Н	Н	Н	Н	Н	H	Н		
L	L	L	L	L	H	H	Н	Н	Н	H	Н		
L	L	Н	L	Н	L	Н	Н	Н	Н	Н	Н		
L	H	L	L	Н	Н	L	Н	Н	Н	Н	Н		
L	Н	Н	L	Н	Н	Н	L	Н	H	Н	Н		
H	L	L	L	Н	Н	Н	Н	L	Н	Н	Н		
Н	L	Н	L	Н	H	Н	Н	Н	L	Н	H		
H	H	L	L	Н	Н	Н	Н	Н	Н	L	Н		
Н	Н	Н	L	Н	Н	Н	Н	Н	Н	Н	L		

- Notes) 1. C; input 1C and 2C connected together
  - 2. G; inputs 1G and 2G connected together
  - 3. H; high level, L; low level, X; irrelevant



## **HD74LS156**

#### **ELECTRICAL CHARACTERISTICS** ( $T_a = -20 \sim +75^{\circ}C$ )

Item	Symbol	Test Condition	min	typ*	max	Unit	
	ViH			2.0	_	_	v
Input voltage	VIL			_	_	0.8	v
Output current	Іон	$V_{CC} = 4.75 \text{V}, V_{IH} = 2 \text{V}, V_{IL} = 0.8 \text{V},$	_		100	μA	
Output voltage			$I_{OL} = 4 \text{mA}$	-	_	0.4	ν
	Vol	$V_{CC} = 4.75 \text{V}, V_{IH} = 2 \text{V}, V_{IL} = 0.8 \text{V}$	<i>lo L</i> = 8mA			0.5	v
	Iн	$V_{CC} = 5.25 \text{V},  V_I = 2.7 \text{V}$		.att.		20	μA
Input current	IIL	$V_{\rm CC} = 5.25 \text{V},  V_{I} = 0.4 \text{V}$			-	-0.4	mA
	Ii	$V_{CC} = 5.25 \text{V},  V_I = 7 \text{V}$				0.1	mA
Supply current**	lcc	$V_{CC}=5.25V$		-	6.1	10	mА
Input clamp voltage	Vik	$V_{CC} = 4.75 \text{V}, I_{IN} = -18 \text{mA}$		_		-1.5	v

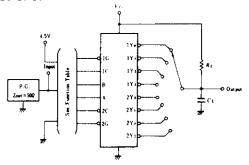
<sup>•</sup> *VCC*=5V, *Ta*=25°C

#### **ESWITCHING CHARACTERISTICS** ( $V_{CC}=5V$ , $T_a=25^{\circ}C$ )

Îtem	Symbol	Inputs	Output	Level of logic	Test Conditions	min	typ	max	Unit
Propagation delay time	telh	A, B, 2C, 1G or 2G	Y	2	$C_L = 15 \text{pF}, \qquad -$ $R_L = 2 \text{k} \Omega \qquad -$	-	25	40	ns
	tphl	A, B, 2C, 1G or 2G	Y	2		_	34	51	
	tri.H	A or B	Y	3		-	31	46	
	tehl	A or B	Y	3		_	34	51	
	trlH	1C	Y	3		-	32	48	
	tPHL	1C	Y	3			32	48	

#### **ETESTING METHOD**

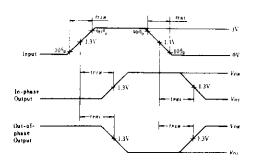
#### 1) Test Circuit



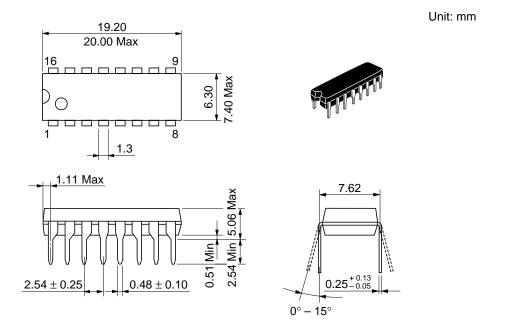
Notes) 1. Input pulse;  $t_{TLH} \le 15$ ns,  $t_{THL} \le 6$ ns, PRR = 1MHz, duty cycle=50%.

2.  $C_L$  includes probe and jig capacitance.

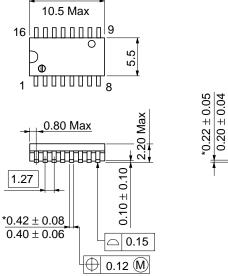
#### Waveform



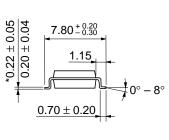
<sup>\*\*</sup> I<sub>CC</sub> is measured with outputs open, A, B, and 1C inputs at 4.5V, and 2C, 1G, and 2G inputs grounded.



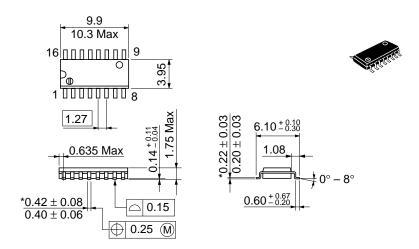




10.06



Unit: mm



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